



14 Bit, 105 MSPS

# Analog-to-Digital Converter

# **FEATURES**

- 14 Bit Resolution
- 105 MSPS Maximum Sample Rate
- SNR = 74 dBc at 105 MSPS and 50-MHz IF
- SFDR = 93 dBc at 105 MSPS and 50-MHz IF
- 2.2 V<sub>pp</sub> Differential Input Range
- 5 V Supply Operation
- 3.3 V CMOS Compatible Outputs
- 1.9 W Total Power Dissipation
- 2s Complement Output Format
- On-Chip Input Analog Buffer, Track and Hold, and Reference Circuit

- 52 Pin HTQFP Package With Exposed Heatsink
- Pin Compatible to the AD6644/45
- Industrial Temperature Range = −40°C to 85°C

SLWS157B - JANUARY 2005 - REVISED JANUARY 2010

# **APPLICATIONS**

- Single and Multichannel Digital Receivers
- Base Station Infrastructure
- Instrumentation
- Video and Imaging

#### RELATED DEVICES

• Clocking: CDC7005

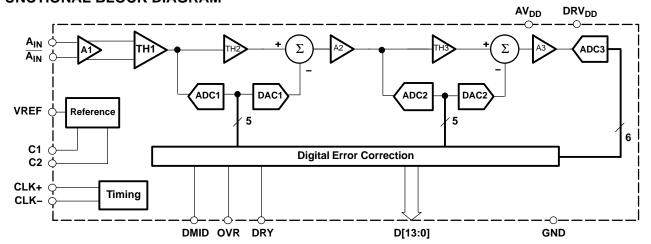
Amplifiers: OPA695, THS4509

# **DESCRIPTION**

The ADS5424 is a 14 bit 105 MSPS analog-to-digital converter (ADC) that operates from a 5 V supply, while providing 3.3 V CMOS compatible digital outputs. The ADS5424 input buffer isolates the internal switching of the on-chip Track and Hold (T&H) from disturbing the signal source. An internal reference generator is also provided to further simplify the system design. The ADS5424 has outstanding low noise and linearity, over input frequency. With only a 2.2 V<sub>PP</sub> input range, simplifies the design of multicarrier applications, where the carriers are selected on the digital domain.

The ADS5424 is available in a 52 pin HTQFP with heatsink package and is pin compatible to the AD6645. The ADS5424 is built on state of the art Texas Instruments complementary bipolar process (BiCom3) and is specified over full industrial temperature range (–40°C to 85°C).

# **FUNCTIONAL BLOCK DIAGRAM**



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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### NOTE:

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

# **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

		ADS5424	UNIT	
Committee ma	AV <sub>DD</sub> to GND	6	V	
Supply voltage	DRV <sub>DD</sub> to GND	5	V	
Analog input to 0	GND	-0.3 to AV <sub>DD</sub> + 0.3		
Clock input to G	ND	-0.3 to AV <sub>DD</sub> + 0.3	V	
CLK to CLK		±2.5	V	
Digital data outp	ut to GND	-0.3 to DRV <sub>DD</sub> + 0.3	V	
Operating temper	erature range	-40 to 85	°C	
Maximum junction temperature		150	°C	
Storage tempera	ture range	-65 to 150	°C	

<sup>(1)</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

# THERMAL CHARACTERISTICS(1)

PARAMETER	TEST CONDITIONS	TYP	UNIT
$\theta_{JA}$	Soldered slug, no airflow	22.5	°C/W
$\theta_{JA}$	Soldered slug, 200-LPFM airflow	15.8	°C/W
$\theta_{JA}$	Unsoldered slug, no airflow	33.3	°C/W
$\theta_{JA}$	Unsoldered slug, 200-LPFM airflow	25.9	°C/W
θЈС	Bottom of package (heatslug)	2	°C/W

<sup>(1)</sup> Using 25 thermal vias (5 x 5 array). See the Application Section.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe

proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because small parametric changes could cause the device not to meet its published specifications.

#### RECOMMENDED OPERATING CONDITIONS

PARAMETER	MIN	TYP	MAX	UNIT
Supplies				
Analog supply voltage, AV <sub>DD</sub>	4.75	5	5.25	V
Output driver supply voltage, DRV <sub>DD</sub>	3	3.3	3.6	V
Analog Input				
Differential input range		2.2		$V_{PP}$
Input common-mode voltage, V <sub>CM</sub>		2.4		V
Digital Output				
Maximum output load		10		pF
Clock Input				
ADCLK input sample rate (sine wave) 1/t <sub>C</sub>	30		105	MSPS
Clock amplitude, sine wave, differential <sup>(1)</sup>		3		V <sub>PP</sub>
Clock duty cycle <sup>(2)</sup>		50%		
Open free-air temperature range	-40		85	°C

- (1) See Figure 22 and Figure 23 for more information.
- (2) See Figure 21 for more information.



# **ELECTRICAL CHARACTERISTICS**

Over full temperature range ( $T_{MIN} = -40^{\circ}C$  to  $T_{MAX} = 85^{\circ}C$ ), sampling rate = 105 MSPS, 50% clock duty cycle,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, -1 dBFS differential input, and 3 V<sub>PP</sub> differential sinusoidal clock, unless otherwise noted

PARAMETER	TEST CONDIT	TONS	MIN	TYP	MAX	UNIT	
Resolution				14		Bits	
Analog Inputs	<u> </u>					•	
Differential input range				2.2		$V_{PP}$	
Differential input resistance	See Figure 32			1		kΩ	
Differential input capacitance	See Figure 32			1.5		pF	
Analog input bandwidth				570		MHz	
Internal Reference Voltages	•					•	
Reference voltage, V <sub>REF</sub>				2.4		V	
Dynamic Accuracy	•					•	
No missing codes				Tested			
Differential linearity error, DNL	f <sub>IN</sub> = 5 MHz		-0.95	±0.5	1.5	LSB	
Integral linearity error, INL	f <sub>IN</sub> = 5 MHz			±1.5		LSB	
Offset error			-5	0	5	mV	
Offset temperature coefficient				1.7		ppm/°C	
Gain error			-5	0.9	5	%FS	
PSRR				1		mV/V	
Gain temperature coefficient				77		ppm/°C	
Power Supply	•						
Analog gunnhi gurrant I	V full cools f 70 MHz	F <sub>S</sub> = 92.16 MSPS		355		A	
Analog supply current, I <sub>AVDD</sub>	$V_{IN}$ = full scale, $f_{IN}$ = 70 MHz	F <sub>S</sub> = 105 MSPS		355	410	mA	
Output buffer aupply aurrent 1	V - full cools f - 70 MHz	F <sub>S</sub> = 92.16 MSPS		38		m Λ	
Output buffer supply current, I <sub>DRVDD</sub>	$V_{IN}$ = full scale, $f_{IN}$ = 70 MHz	F <sub>S</sub> = 105 MSPS		40	47	mA	
Power dissipation	Total power with 10-pF load	F <sub>S</sub> = 92.16 MSPS		1.9		W	
rowei uissipalion	on each digital output to ground, f <sub>IN</sub> = 70 MHz	F <sub>S</sub> = 105 MSPS		1.9	2.2	VV	
Power-up time		F <sub>S</sub> = 105 MSPS		20	100	ms	



# **ELECTRICAL CHARACTERISTICS**

Over full temperature range ( $T_{MIN} = -40^{\circ}C$  to  $T_{MAX} = 85^{\circ}C$ ), sampling rate = 105 MSPS, 50% clock duty cycle,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, -1 dBFS differential input, and 3  $V_{PP}$  differential sinusoidal clock, unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Dynamic AC Characteristics								
	f <sub>IN</sub> = 10 MHz	F <sub>S</sub> = 92.16 MSPS		74.5		dBc		
	IIN = 10 IVII IZ	F <sub>S</sub> = 105 MSPS		74.4		ubc		
	f <sub>IN</sub> = 30 MHz	F <sub>S</sub> = 92.16 MSPS		74.4		dBc		
	1 N = 30 W1 12	F <sub>S</sub> = 105 MSPS	73	74.3		dBc		
	f <sub>IN</sub> = 50 MHz	F <sub>S</sub> = 92.16 MSPS		74.2		dBc		
	1 N = 30 W1 12	F <sub>S</sub> = 105 MSPS		74.2		ubc		
Signal to paiga ratio SND	f <sub>IN</sub> = 70 MHz	F <sub>S</sub> = 92.16 MSPS		74		dBc		
Signal-to-noise ratio, SNR	1 N = 70 WI 12	F <sub>S</sub> = 105 MSPS	72.5	74		ubc		
	f = 100 MHz	F <sub>S</sub> = 92.16 MSPS		73.5		dBc		
	f <sub>IN</sub> = 100 MHz	F <sub>S</sub> = 105 MSPS		73.5		ubc		
	f 170 MHz	F <sub>S</sub> = 92.16 MSPS		72		dDa		
	f <sub>IN</sub> = 170 MHz	F <sub>S</sub> = 105 MSPS		72		dBc		
	f 220 MH=	F <sub>S</sub> = 92.16 MSPS		71.5		dDa		
	f <sub>IN</sub> = 230 MHz	F <sub>S</sub> = 105 MSPS		71.5		dBc		
	f 40 MH I-	F <sub>S</sub> = 92.16 MSPS		94		dD.		
	$f_{IN} = 10 \text{ MHz}$	F <sub>S</sub> = 105 MSPS		93		dBc		
	f <sub>IN</sub> = 30 MHz	F <sub>S</sub> = 92.16 MSPS		95		dBc		
		F <sub>S</sub> = 105 MSPS	85	95		dBc		
	f <sub>IN</sub> = 50 MHz	F <sub>S</sub> = 92.16 MSPS		94		JD.		
		F <sub>S</sub> = 105 MSPS		93		dBc		
	f <sub>IN</sub> = 70 MHz	F <sub>S</sub> = 92.16 MSPS		89		dD.		
Spurious-free dynamic range, SFDR		F <sub>S</sub> = 105 MSPS		88		dBc		
	f 400 MUL	F <sub>S</sub> = 92.16 MSPS		88		JD.		
	f <sub>IN</sub> = 100 MHz	F <sub>S</sub> = 105 MSPS		87		dBc		
	f 470 MILE	F <sub>S</sub> = 92.16 MSPS		73		JD -		
	f <sub>IN</sub> = 170 MHz	F <sub>S</sub> = 105 MSPS		73		dBc		
	f 000 NALL	F <sub>S</sub> = 92.16 MSPS		64		JD -		
	f <sub>IN</sub> = 230 MHz	F <sub>S</sub> = 105 MSPS		64		dBc		
	f 40 MUL	F <sub>S</sub> = 92.16 MSPS		74.4		JD -		
	$f_{IN} = 10 \text{ MHz}$	F <sub>S</sub> = 105 MSPS		74.3		dBc		
	f 00 MILE	F <sub>S</sub> = 92.16 MSPS		74.3		JD.		
	$f_{IN} = 30 \text{ MHz}$	F <sub>S</sub> = 105 MSPS	72.8	74.3		dBc		
	f 50 MH	F <sub>S</sub> = 92.16 MSPS		74.1		JD.		
	$f_{IN} = 50 \text{ MHz}$	F <sub>S</sub> = 105 MSPS		74		dBc		
Signal-to-noise + distortion, SINAD	f 70 MILE	F <sub>S</sub> = 92.16 MSPS		74		-ID-		
	$f_{IN} = 70 \text{ MHz}$	F <sub>S</sub> = 105 MSPS		73.9		dBc		
	£ 400 MIL	F <sub>S</sub> = 92.16 MSPS		73.3		۹D-		
	f <sub>IN</sub> = 100 MHz	F <sub>S</sub> = 105 MSPS		73.3		dBc		
		F <sub>S</sub> = 92.16 MSPS		69.3		JD.		
	f <sub>IN</sub> = 170 MHz	F <sub>S</sub> = 105 MSPS		69.1		dBc		
		F <sub>S</sub> = 92.16 MSPS		63.4		ı.		
	f <sub>IN</sub> = 230 MHz	F <sub>S</sub> = 105 MSPS		63.4		dBc		



# **ELECTRICAL CHARACTERISTICS**

Over full temperature range ( $T_{MIN} = -40^{\circ}C$  to  $T_{MAX} = 85^{\circ}C$ ), sampling rate = 105 MSPS, 50% clock duty cycle,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, -1 dBFS differential input, and 3  $V_{PP}$  differential sinusoidal clock, unless otherwise noted

PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
	f <sub>IN</sub> = 10 MHz	100	dBc
	f <sub>IN</sub> = 30 MHz	105	dBc
	f <sub>IN</sub> = 50 MHz	98	dBc
Second harmonic, HD2	f <sub>IN</sub> = 70 MHz	98	dBc
	f <sub>IN</sub> = 100 MHz	98	dBc
	f <sub>IN</sub> = 170 MHz	98	dBc
	f <sub>IN</sub> = 230 MHz	96	dBc
	f <sub>IN</sub> = 10 MHz	93	dBc
	f <sub>IN</sub> = 30 MHz	dBc	
Third have a six LIDO	$f_{IN} = 10 \text{ MHz}$ $f_{IN} = 30 \text{ MHz}$ $f_{IN} = 50 \text{ MHz}$ $f_{IN} = 100 \text{ MHz}$ $f_{IN} = 170 \text{ MHz}$ $f_{IN} = 230 \text{ MHz}$	93	dBc
Third harmonic, HD3	f <sub>IN</sub> = 100 MHz	87	dBc
	f <sub>IN</sub> = 170 MHz	73	dBc
	f <sub>IN</sub> = 230 MHz	64	dBc
	f <sub>IN</sub> = 10 MHz	93	dBc
	f <sub>IN</sub> = 30 MHz	95	dBc
	f <sub>IN</sub> = 50 MHz	93	dBc
Worst-harmonic / spur (other than HD2 and HD3)	$\begin{split} f_{IN} &= 70 \text{ MHz} \\ f_{IN} &= 100 \text{ MHz} \\ f_{IN} &= 170 \text{ MHz} \\ f_{IN} &= 120 \text{ MHz} \\ f_{IN} &= 230 \text{ MHz} \\ f_{IN} &= 10 \text{ MHz} \\ f_{IN} &= 30 \text{ MHz} \\ f_{IN} &= 50 \text{ MHz} \\ f_{IN} &= 100 \text{ MHz} \\ f_{IN} &= 170 \text{ MHz} \\ f_{IN} &= 230 \text{ MHz} \\ \end{split}$ er than HD2 $\begin{split} f_{IN} &= 10 \text{ MHz} \\ f_{IN} &= 50 \text{ MHz} \\ f_{IN} &= 10 \text{ MHz} \\ f_{IN} &= 30 \text{ MHz} \\ \end{split}$ er than HD2 $\begin{split} f_{IN} &= 10 \text{ MHz} \\ f_{IN} &= 50 \text{ MHz} \\ f_{IN} &= 70 \text{ MHz} \\ f_{IN} &= 100 \text{ MHz} \\ \vdots \\ f_{IN} &= 170 \text{ MHz} \\ \end{split}$	88	dBc
and noo)	f <sub>IN</sub> = 100 MHz	88	dBc
	f <sub>IN</sub> = 170 MHz	88	dBc
	f <sub>IN</sub> = 230 MHz	88	dBc
RMS idle channel noise	Input pins tied together	0.9	LSB

# **DIGITAL CHARACTERISTICS**

Over full temperature range ( $T_{MIN} = -40$ °C to  $T_{MAX} = 85$ °C),  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, unless otherwise noted

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Digital Outputs					
Low-level output voltage	$C_{LOAD} = 10 \text{ pF}^{(1)}$		0.1	0.6	V
High-level output voltage	$C_{LOAD} = 10 \text{ pF}^{(1)}$	2.6	3.2		V
Output capacitance			3		pF
DMID			DRV <sub>DD</sub> /2		٧

<sup>(1)</sup> Equivalent capacitance to ground of (load + parasitics of transmission lines).



# TIMING CHARACTERISTICS(3)

Over full temperature range,  $AV_{DD} = 5 \text{ V}$ ,  $DRV_{DD} = 3.3 \text{ V}$ , sampling rate = 105 MSPS

DESCRIPTION	MIN	TYP	MAX	UNIT
•	•			•
Aperture delay		500		ps
Clock slope independent aperture uncertainity (jitter)		150		fs
Clock slope dependent jitter factor		50		μV
Clock period		9.5		ns
Clock pulsewidth high		4.75		ns
Clock pulsewidth low		4.75		ns
RY)				
Clock rising 50% to DRY falling 50%	2.8	3.9	4.7	ns
Clock rising 50% to DRY rising 50%		t <sub>DR</sub> +		ns
Clock rising 50% to DRY rising 50% with 50% duty cycle clock	7.6	8.7	9.5	ns
Data V <sub>OL</sub> to data V <sub>OH</sub> (rise time)		2		ns
Data V <sub>OH</sub> to data V <sub>OL</sub> (fall time)		2		ns
Latency		3		Cycles
Valid DATA <sup>(2)</sup> to clock 50% with 50% duty cycle clock (setup time)	1.8	3.4		ns
Clock 50% to invalid DATA <sup>(2)</sup> (hold time)	2.6	3.6		ns
TA, OVR <sup>(4)</sup>	•			
Valid DATA <sup>(2)</sup> to DRY 50% with 50% duty cycle clock (setup time)	1.8	2.6		ns
DRY 50% to invalid DATA <sup>(2)</sup> with 50% duty cycle clock (hold time)	3.9	4.4		ns
	Aperture delay  Clock slope independent aperture uncertainity (jitter)  Clock slope dependent jitter factor  Clock period  Clock pulsewidth high  Clock pulsewidth low  RY)  Clock rising 50% to DRY falling 50%  Clock rising 50% to DRY rising 50%  Clock rising 50% to DRY rising 50% with 50% duty cycle clock  Data V <sub>OL</sub> to data V <sub>OH</sub> (rise time)  Data V <sub>OH</sub> to data V <sub>OL</sub> (fall time)  Latency  Valid DATA <sup>(2)</sup> to clock 50% with 50% duty cycle clock (setup time)  Clock 50% to invalid DATA <sup>(2)</sup> (hold time)  ITA, OVR <sup>(4)</sup> Valid DATA <sup>(2)</sup> to DRY 50% with 50% duty cycle clock (setup time)	Aperture delay  Clock slope independent aperture uncertainity (jitter)  Clock slope dependent jitter factor  Clock period  Clock pulsewidth high  Clock pulsewidth low  RY)  Clock rising 50% to DRY falling 50%  Clock rising 50% to DRY rising 50%  Clock rising 50% to DRY rising 50%  Clock rising 50% to DRY rising 50% with 50% duty cycle clock  7.6  Data V <sub>OL</sub> to data V <sub>OH</sub> (rise time)  Data V <sub>OH</sub> to data V <sub>OL</sub> (fall time)  Latency  Valid DATA <sup>(2)</sup> to clock 50% with 50% duty cycle clock (setup time)  1.8  Clock 50% to invalid DATA <sup>(2)</sup> (hold time)  Z.6  ITA, OVR <sup>(4)</sup> Valid DATA <sup>(2)</sup> to DRY 50% with 50% duty cycle clock (setup time)  1.8	Aperture delay 500 Clock slope independent aperture uncertainity (jitter) 150 Clock slope dependent jitter factor 50  Clock period 9.5 Clock pulsewidth high 4.75 Clock pulsewidth low 4.75 Clock pulsewidth low 4.75  Clock rising 50% to DRY falling 50% 2.8 3.9 Clock rising 50% to DRY rising 50% 4 Clock rising 50% to DRY rising 50% 50% 6  Lock rising 50% to DRY rising 50% 6  Data V <sub>OL</sub> to data V <sub>OH</sub> (rise time) 2 Latency 3 Valid DATA <sup>(2)</sup> to clock 50% with 50% duty cycle clock (setup time) 1.8 3.4 Clock 50% to invalid DATA <sup>(2)</sup> (hold time) 2.6 3.6  ITA, OVR <sup>(4)</sup> Valid DATA <sup>(2)</sup> to DRY 50% with 50% duty cycle clock (setup time) 1.8 2.6	Aperture delay   500

<sup>(1)</sup> See Figure 21 for more information.(2) See V<sub>OH</sub> and V<sub>OL</sub> levels.

<sup>(4)</sup> Data is updated with clock rising edge or DRY falling edge.

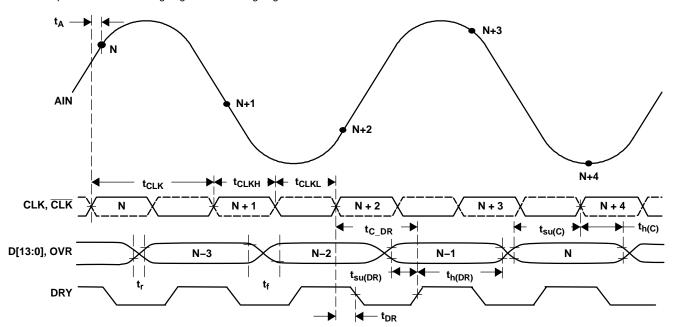
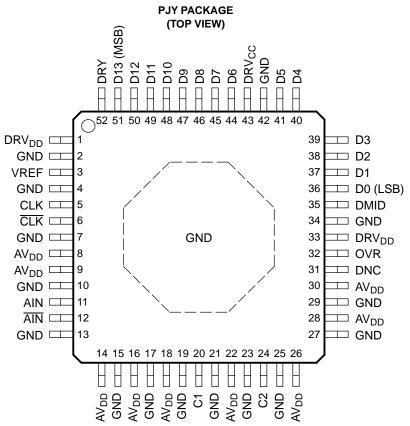


Figure 1. Timing Diagram

<sup>(3)</sup> All values obtained from design and characterization.



# **PIN CONFIGURATION**



# **PIN ASSIGNMENTS**

TER	MINAL						
NAME	NO.	DESCRIPTION					
DRV <sub>DD</sub>	1, 33, 43	3.3 V power supply, digital output stage only					
GND	2, 4, 7, 10, 13, 15, 17, 19, 21, 23, 25, 27, 29, 34, 42	Ground					
VREF	3	2.4 V reference. Bypass to ground with a 0.1-μF microwave chip capacitor.					
CLK	5	Clock input. Conversion initiated on rising edge.					
CLK	6	Complement of CLK, differential input					
$AV_{DD}$	8, 9, 14, 16, 18, 22, 26, 28, 30	5 V analog power supply					
AIN	11	Analog input					
AIN	12	Complement of AIN, differential analog input					
C1	20	Internal voltage reference. Bypass to ground with a 0.1-µF chip capacitor.					
C2	24	Internal voltage reference. Bypass to ground with a 0.1-µF chip capacitor.					
DNC	31	Do not connect					
OVR	32	Overrange bit. A logic level high indicates the analog input exceeds full scale.					
DMID	35	Output data voltage midpoint. Approximately equal to (DV <sub>CC</sub> )/2					
D0 (LSB)	36	Digital output bit (least significant bit); two's complement					
D1-D5, D6-D12	37–41, 44–50	Digital output bits in two's complement					
D13 (MSB)	51	Digital output bit (most significant bit); two's complement					
DRY	52	Data ready output					



#### **DEFINITION OF SPECIFICATIONS**

# **Analog Bandwidth**

The analog input frequency at which the power of the fundamental is reduced by 3 dB with respect to the low frequency value.

#### **Aperture Delay**

The delay between the rising edge of the input sampling clock and the actual time at which the sampling occurs.

# **Aperture Uncertainty (Jitter)**

The sample-to-sample variation in aperture delay.

# Clock Pulse Width/Duty Cycle

The duty cycle of a clock signal is the ratio of the time the clock signal remains at a logic high (clock pulse width) to the period of the clock signal. Duty cycle is typically expressed as a percentage. A perfect differential sine wave clock results in a 50% duty cycle.

#### **Maximum Conversion Rate**

The maximum sampling rate at which certified operation is given. All parametric testing is performed at this sampling rate unless otherwise noted.

#### **Minimum Conversion Rate**

The minimum sampling rate at which the ADC functions.

#### **Differential Nonlinearity (DNL)**

An ideal ADC exhibits code transitions at analog input values spaced exactly 1 LSB apart. The DNL is the deviation of any single step from this ideal value, measured in units of LSB.

#### Integral Nonlinearity (INL)

The INL is the deviation of the ADC's transfer function from a best fit line determined by a least squares curve fit of that transfer function, measured in units of LSB.

#### **Gain Error**

The gain error is the deviation of the ADC's actual input full-scale range from its ideal value. The gain error is given as a percentage of the ideal input full-scale range.

#### Offset Error

The offset error is the difference, given in number of LSBs, between the ADC's actual value average idle channel output code and the ideal average idle channel output code. This quantity is often mapped into mV.

# **Temperature Drift**

The temperature drift coefficient (with respect to gain error and offset error) specifies the change per degree celcius of the paramter from  $T_{MIN}$  or  $T_{MAX}$ . It is computed as the maximum variation of that parameter over the whole temperature range divided by  $T_{MAX} - T_{MIN}$ .

# Signal-to-Noise Ratio (SNR)

SNR is the ratio of the power of the fundamental  $(P_S)$  to the noise floor power  $(P_N)$ , excluding the power at dc and the first five harmonics.

$$SNR = 10Log_{10} \frac{P_S}{P_N}$$

SNR is either given in units of dBc (dB to carrier) when the absolute power of the fundamental is used as the reference or dBFS (dB to full scale) when the power of the fundamental is extrapolated to the converter's full-scale range.

#### Signal-to-Noise and Distortion (SINAD)

SINAD is the ratio of the power of the fundamental ( $P_S$ ) to the power of all the other spectral components including noise ( $P_N$ ) and distortion ( $P_D$ ), but excluding dc.

$$SINAD = 10Log_{10} \frac{P_S}{P_N + P_D}$$

SINAD is either given in units of dBc (dB to carrier) when the absolute power of the fundamental is used as the reference or dBFS (dB to full scale) when the power of the fundamental is extrapolated to the converter's full-scale range.



# **Total Harmonic Distortion (THD)**

THD is the ratio of the fundamental power  $(P_S)$  to the power of the first five harmonics  $(P_D)$ .

$$THD = 10Log_{10} \frac{P_S}{P_D}$$

THD is typically given in units of dBc (dB to carrier).

# Spurious-Free Dynamic Range (SFDR)

The ratio of the power of the fundamental to the highest other spectral component (either spur or harmonic). SFDR is typically given in units of dBc (dB to carrier).

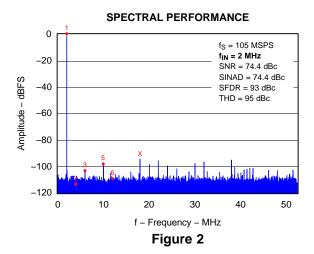
#### **Two-Tone Intermodulation Distortion**

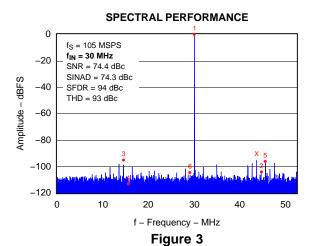
IMD3 is the ratio of the power of the fundamental (at frequiencies  $f_1$ ,  $f_2$ ) to the power of the worst spectral component at either frequency  $2f_1 - f_2$  or  $2f_2 - f_1$ ). IMD3 is either given in units of dBc (dB to carrier) when the absolute power of the fundamental is used as the reference or dBFS (dB to full scale) when it is referred to the full-scale range.



# TYPICAL CHARACTERISTICS

Typical values are at  $T_A = 25^{\circ}$ C,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, differential input amplitude = -1 dBFS, sampling rate = 105 MSPS, 3  $V_{PP}$  sinusoidal clock, 50% duty cycle, 16k FFT points, unless otherwise noted





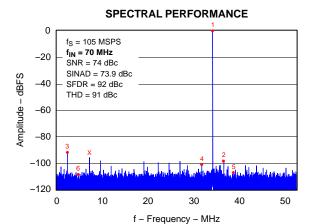
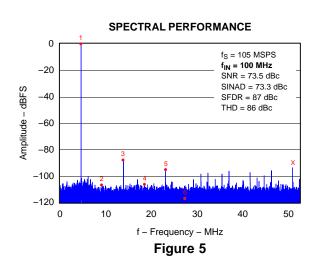
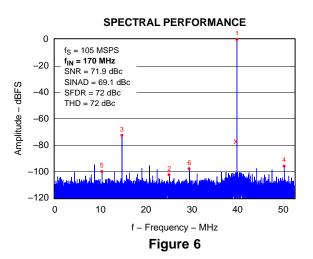
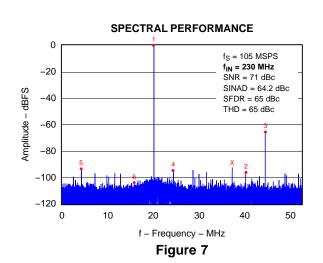


Figure 4

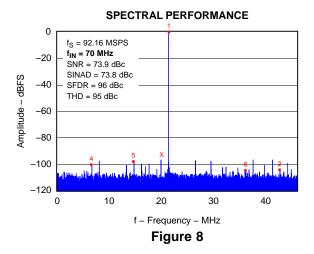


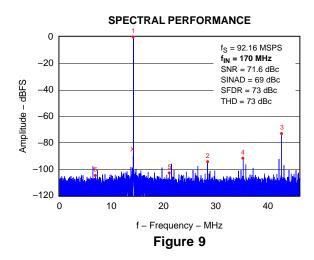


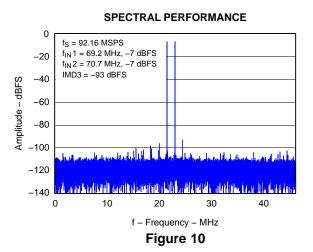


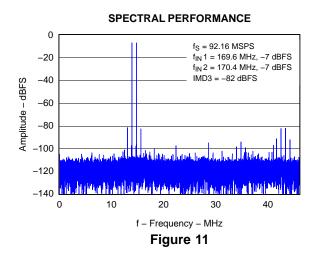


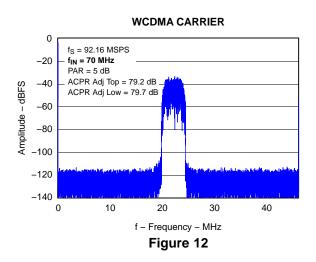
Typical values are at  $T_A = 25^{\circ}C$ ,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, differential input amplitude = -1 dBFS, sampling rate = 105 MSPS, 3  $V_{PP}$  sinusoidal clock, 50% duty cycle, 16k FFT points, unless otherwise noted

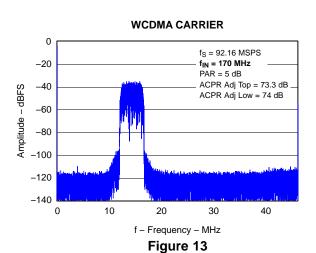














Typical values are at T<sub>A</sub> = 25°C, AV<sub>DD</sub> = 5 V, DRV<sub>DD</sub> = 3.3 V, differential input amplitude = -1 dBFS, sampling rate = 105 MSPS, 3 V<sub>PP</sub> sinusoidal clock, 50% duty cycle, 16k FFT points, unless otherwise noted

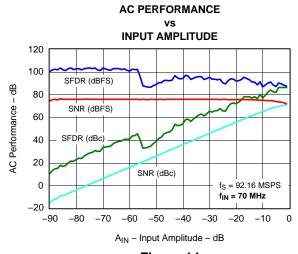


Figure 14

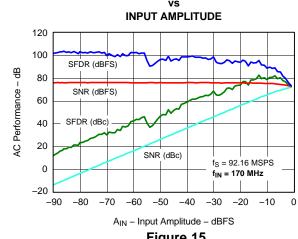


Figure 15

**AC PERFORMANCE** 

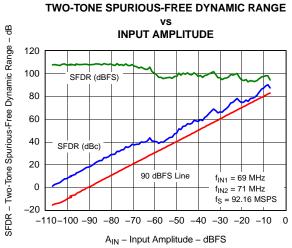


Figure 16

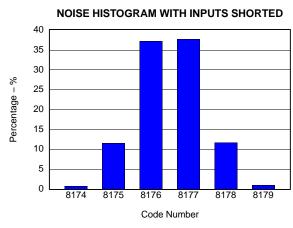
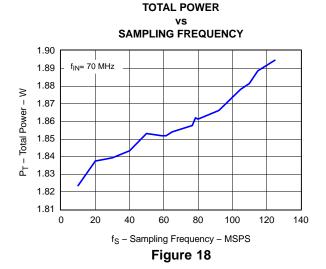


Figure 17



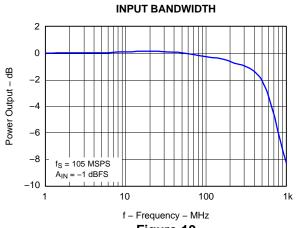


Figure 19



Typical values are at  $T_A = 25^{\circ}C$ ,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, differential input amplitude = -1 dBFS, sampling rate = 105 MSPS, 3  $V_{PP}$  sinusoidal clock, 50% duty cycle, 16k FFT points, unless otherwise noted

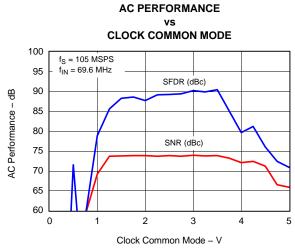


Figure 20

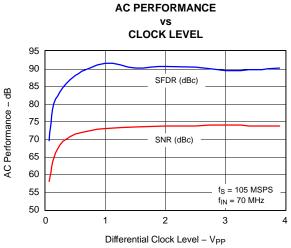
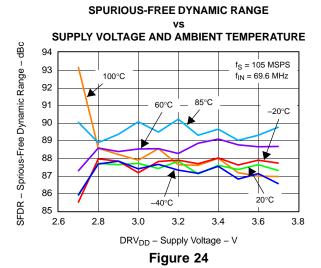


Figure 22





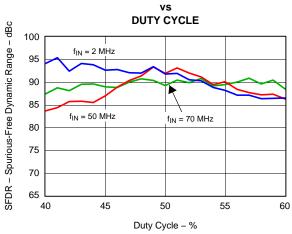


Figure 21

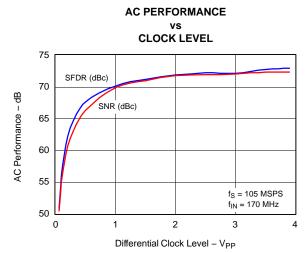
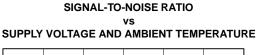


Figure 23



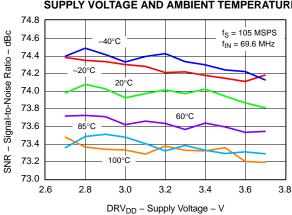


Figure 25



Typical values are at  $T_A = 25^{\circ}C$ ,  $AV_{DD} = 5 V$ ,  $DRV_{DD} = 3.3 V$ , differential input amplitude = -1 dBFS, sampling rate = 105 MSPS,  $3 V_{PP}$  sinusoidal clock, 50% duty cycle, 16k FFT points, unless otherwise noted

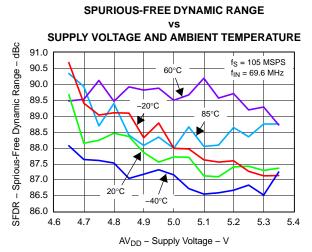


Figure 26

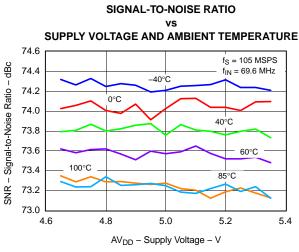


Figure 27

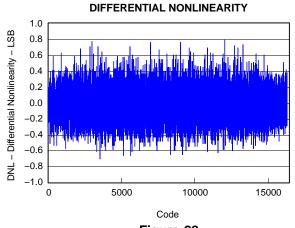


Figure 28

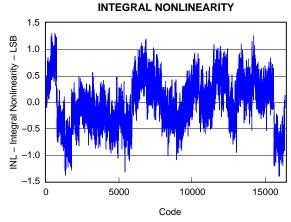


Figure 29



Typical values are at  $T_A = 25$ °C,  $AV_{DD} = 5$  V,  $DRV_{DD} = 3.3$  V, differential input amplitude = -1 dBFS, sampling rate = 105 MSPS, 3 V<sub>PP</sub> sinusoidal clock, 50% duty cycle, 16k FFT points, unless otherwise noted

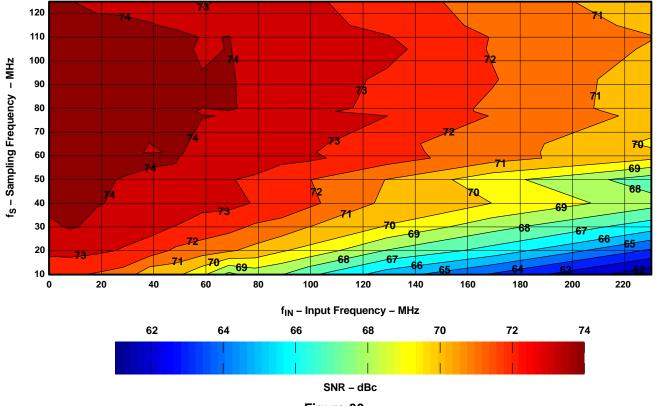


Figure 30.

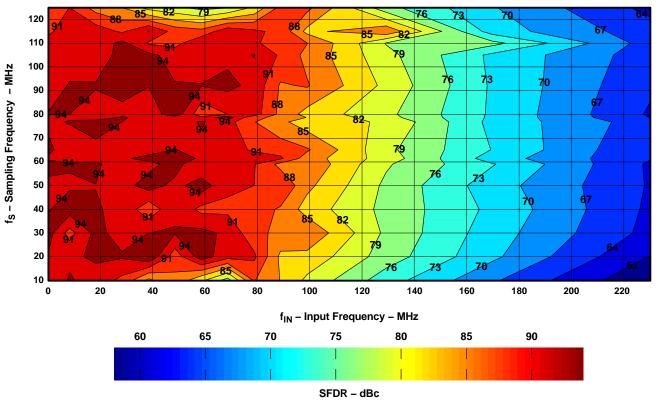


Figure 31.



# **EQUIVALENT CIRCUITS**

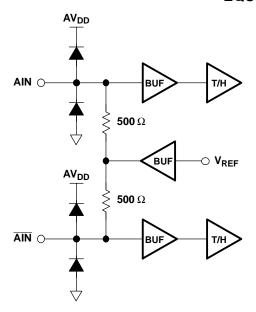


Figure 32. Analog Input

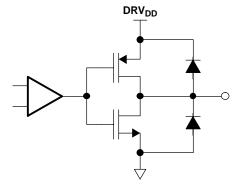


Figure 33. Digital Output

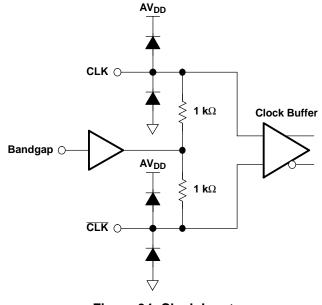


Figure 34. Clock Input

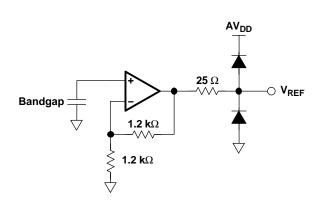


Figure 35. Reference

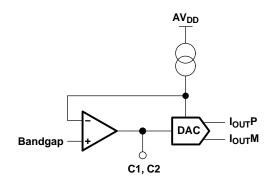


Figure 36. Decoupling Pin

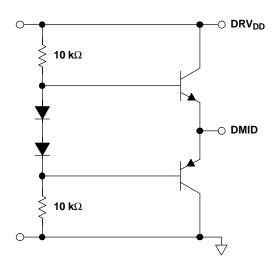


Figure 37. DMID Generation



#### THEORY OF OPERATION

The ADS5424 is a 14 bit, 105 MSPS, monolithic pipeline analog to digital converter. Its bipolar analog core operates from a 5 V supply, while the output uses 3.3 V supply for compatibility with the CMOS family. The conversion process is initiated by the rising edge of the external input clock. At that instant, the differential input signal is captured by the input track and hold (T&H) and the input sample is sequentially converted by a series of small resolution stages, with the outputs combined in a digital correction logic block. Both the rising and the falling clock edges are used to propagate the sample through the pipeline every half clock cycle. This process results in a data latency of three clock cycles, after which the output data is available as a 14 bit parallel word, coded in binary two's complement format.

#### INPUT CONFIGURATION

The analog input for the ADS5424 (see Figure 32) consists of an analog differential buffer followed by a bipolar track-and-hold. The analog buffer isolates the source driving the input of the ADC from any internal switching. The input common mode is set internally through a 500  $\Omega$  resistor connected from 2.4 V to each of the inputs. This results in a differential input impedance of 1 k $\Omega$ .

For a full-scale differential input, each of the differential lines of the input signal (pins 11 and 12) swings symmetrically between 2.4 +0.55 V and 2.4 –0.55 V. This means that each input is driven with a signal of up to 2.4  $\pm 0.55$  V, so that each input has a maximum signal swing of 1.1  $\ensuremath{\text{V}_{\text{PP}}}$  for a total differential input signal swing

of 2.2  $V_{PP}$ . The maximum swing is determined by the internal reference voltage generator eliminating any external circuitry for this purpose.

The ADS5424 obtains optimum performance when the analog inputs are driven differentially. The circuit in Figure 38 shows one possible configuration using an RF transformer with termination either on the primary or on the secondary of the transformer. If voltage gain is required a step up transformer can be used. For higher gains that would require impractical higher turn ratios on the transformer, a single-ended amplifier driving the transformer can be used (see Figure 39). Another circuit optimized for performance would be the one on Figure 40, using the THS4304 or the OPA695. Texas Instruments has shown excellent performance on this configuration up to 10 dB gain with the THS4304 and at 14 dB gain with the OPA695. For the best performance, they need to be configured differentially after the transformer (as shown) or in inverting mode for the OPA695 (see SBAA113); otherwise, HD2 from the op amps limits the useful frequency.

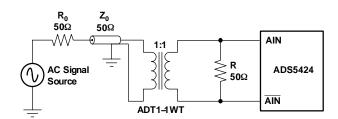


Figure 38. Converting a Single-Ended Input to a Differential Signal Using RF Transformers

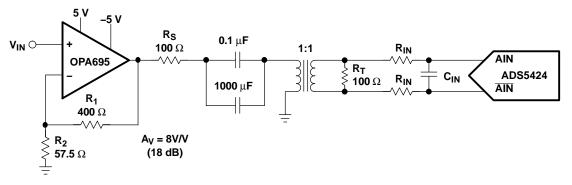


Figure 39. Using the OPA695 With the ADS5424



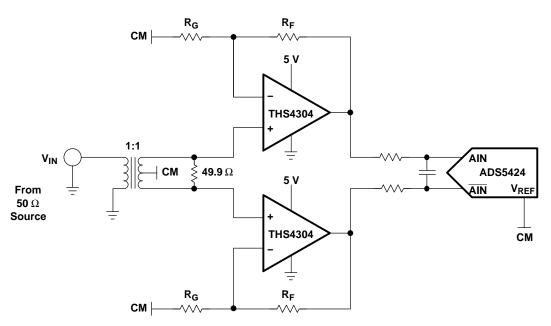


Figure 40. Using the THS4304 With the ADS5424

Besides these, Texas Instruments offers a wide selection of single-ended operational amplifiers (including the THS3201, THS3202 and OPA847) that can be selected depending on the application. An RF gain block amplifier, such as Texas Instrument's THS9001, can also be used with an RF transformer for high input frequency applications. For applications requiring dc-coupling with the signal source, instead of using a topology with three single ended amplifiers, a differential input/differential output amplifier like the THS4509 (see Figure 41) can be used, which minimizes board space and reduce number of components.

Figure 43 shows their combined SNR and SFDR performance versus frequency with -1 dBFS input signal level and sampling at 80MSPS.

On this configuration, the THS4509 amplifier circuit provides 10 dB of gain, converts the single-ended input to differential, and sets the proper input common-mode voltage to the ADS5424.

The 225  $\Omega$  resistors and 2.7 pF capacitor between the THS4509 outputs and ADS5424 inputs (along with the input capacitance of the ADC) limit the bandwidth of the signal to about 100 MHz (–3 dB).

For this test, an Agilent signal generator is used for the signal source. The generator is an ac-coupled 50  $\Omega$  source. A band-pass filter is inserted in series with the input to reduce harmonics and noise from the signal source.

Input termination is accomplished via the 69.8  $\Omega$  resistor and 0.22  $\mu F$  capacitor to ground in conjunction with the input impedance of the amplifier circuit. A 0.22  $\mu F$  capacitor and 49.9  $\Omega$  resistor is inserted to ground across the 69.8  $\Omega$  resistor and 0.22  $\mu F$  capacitor on the alternate input to balance the circuit.

Gain is a function of the source impedance, termination, and 348  $\Omega$  feedback resistor. See the THS4509 data sheet for further component values to set proper 50  $\Omega$  termination for other common gains.

Since the ADS5424 recommended input common-mode voltage is +2.4 V, the THS4509 is operated from a single power supply input with  $V_{S+}$  = +5 V and  $V_{S-}$  = 0 V (ground). This maintains maximum headroom on the internal transistors of the THS4509.



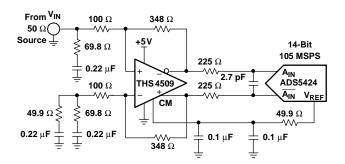


Figure 41. Using the THS4509 With the ADS5424

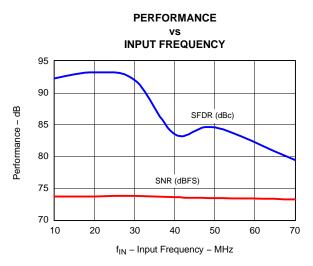


Figure 42. Performance vs Input Frequency for the THS4509 + ADS5424 Configuration

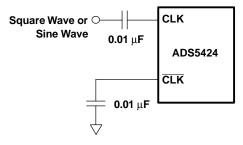


Figure 43. Single-Ended Clock

#### **CLOCK INPUTS**

The ADS5424 clock input can be driven with either a differential clock signal or a single-ended clock input, with little or no difference in performance between both

configurations. In low input frequency applications, where jitter may not be a big concern, the use of single-ended clock (see Figure 43) could save some cost and board space without any trade-off in performance. When driven on this configuration, it is best to connect CLKM (pin 11) to ground with a 0.01  $\mu F$  capacitor, while CLKP is ac-coupled with a 0.01  $\mu F$  capacitor to the clock source, as shown in Figure 40.

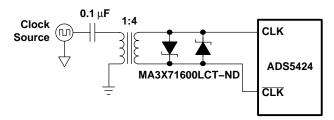


Figure 44. Differential Clock

Nevertheless, for jitter sensitive applications, the use of a differential clock will have some advantages (as with any other ADCs) at the system level. The first advantage is that it allows for common-mode noise rejection at the PCB level. A further analysis (see Clocking High Speed Data Converters, SLYT075) reveals one more advantage. The following formula describes the different contributions to clock jitter:

$$(Jittertotal)^2 = (EXT_jitter)^2 + (ADC_jitter)^2 = (EXT_jitter)^2 + (ADC_int)^2 + (K/clock_slope)^2$$

The first term would represent the external jitter, coming from the clock source, plus noise added by the system on the clock distribution, up to the ADC. The second term is the ADC contribution, which can be divided in two portions. The first does not depend directly on any external factor. That is the best we can get out of our ADC. The second contribution is a term inversely proportional to the clock slope. The faster the slope, the smaller this term will be. As an example, we could compute the ADC jitter contribution from a sinusoidal input clock of 3  $V_{DD}$  amplitude and Fs = 80 MSPS:

ADC\_jitter = sqrt 
$$((150fs)^2 + (5 \times 10^{-5})/(1.5 \times 2 \times PI \times 80 \times 10^{6}))^2) = 164fs$$

The use of differential clock allows for the use of bigger clock amplitudes without exceeding the absolute maximum ratings. This, on the case of sinusoidal clock, results on higher slew rates which minimizes the impact of the jitter factor inversely proportional to the clock slope.



Figure 44 shows this approach. The back-to-back Schottky can be added to limit the clock amplitude in cases where this would exceed the absolute maximum ratings, even when using a differential clock. Figure 22 and Figure 23 show the performance versus input clock amplitude for a sinusoidal clock.

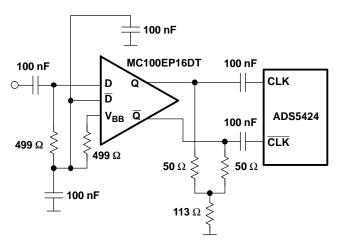


Figure 45. Differential Clock Using PECL Logic

Another possibility is the use of a logic based clock, as PECL. In this case, the slew rate of the edges will most likely be much higher than the one obtained for the same clock amplitude based on a sinusoidal clock. This solution would minimize the effect of the slope dependent ADC jitter. Nevertheless, observe that for the ADS5424, this term is small and has been optimized. Using logic gates to square a sinusoidal clock may not produce the best results as logic gates may not have been optimized to act as comparators, adding too much jitter while squaring the inputs.

The common-mode voltage of the clock inputs is set internally to 2.4 V using internal 1 k $\Omega$  resistors. It is recommended to use an ac coupling, but if for any reason, this scheme is not possible, due to, for instance, asynchronous clocking, the ADS5424 presents a good tolerance to clock common-mode variation (see Figure 20).

Additionally, the internal ADC core uses both edges of the clock for the conversion process. This means that, ideally, a 50% duty cycle should be provided. Figure 21 shows the performance variation of the ADC versus clock duty cycle.

# **DIGITAL OUTPUTS**

The ADC provides 14 data outputs (D13 to D0, with D13 being the MSB and D0 the LSB), a data-ready signal (DRY, pin 52), and an out-of-range indicator (OVR, pin 32) that equals 1 when the output reaches the full-scale limits.

The output format is two's complement. When the input voltage is at negative full scale (around -1.1 V differential), the output will be, from MSB to LSB, 10 0000 0000 0000. Then, as the input voltage is increased, the output switches to 10 0000 0000 0001, 10 0000 0000 0010 and so on until 11 1111 1111 right before mid-scale (when both inputs are tight together if we neglect offset errors). Further increases on input voltage, outputs the word 00 0000 0000 0000, to be followed by 00 0000 0000 0001, 00 0000 0000 0010 and so on until reaching 01 1111 1111 1111 at full-scale input (1.1-V differential).

Although the output circuitry of the ADS5424 has been designed to minimize the noise produced by the transients of the data switching, care must be taken when designing the circuitry reading the ADS5424 outputs. Output load capacitance should be minimized by minimizing the load on the output traces, reducing their length and the number of gates connected to them, and by the use of a series resistor with each pin. Typical numbers on the data sheet tables and graphs are obtained with 100  $\Omega$  series resistor on each digital output pin, followed by a 74AVC16244 digital buffer as the one used in the evaluation board.

#### **POWER SUPPLIES**

The use of low noise power supplies with adequate decoupling is recommended, being the linear supplies the first choice versus switched ones, which tend to generate more noise components that can be coupled to the ADS5424.



The ADS5424 uses two power supplies. For the analog portion of the design, a 5 V AVDD is used, while for the digital outputs supply (DRV<sub>DD</sub>), we recommend the use of 3.3 V. All the ground pins are marked as GND, although AGND pins and DRGND pins are not tied together inside the package. Customers willing to experiment with different grounding schemes should know that AGND pins are 4, 7, 10, 13, 15, 17, 19, 21, 23, 25, 27, and 29, while DRGND pins are 2, 34, and 42. Nevertheless, we recommend that both grounds are tied together externally, using a common ground plane. That is the case on the production test boards and modules provided to customer for evaluation. In order to obtain the best performance, user should layout the board to assure that the digital return currents do not flow under the analog portion of the board. This can be achieved without the need to split the board and just with careful component placing and increasing the number of vias and ground planes.

Finally, notice that the metallic heat sink under the package is also connected to analog ground.

#### LAYOUT INFORMATION

The evaluation board represents a good guideline of how to layout the board to obtain the maximum performance out of the ADS5424. General design rules as the use of multilayer boards, single ground plane for both, analog and digital ADC ground connections and local decoupling ceramic chip capacitors should be applied. The input traces should be isolated from any external source of interference or noise, including the digital outputs as well as the clock traces. Clock should also be isolated from other signals, especially on applications where low jitter is required, as high IF sampling.

Besides performance oriented rules, special care has to be taken when considering the heat dissipation out of the device. The thermal heat sink (octagonal, with 2,5 mm on each side) should be soldered to the board, and provision for more than 16 ground vias should be made. The thermal package information describes the T<sub>JA</sub> values obtained on the different configurations.





4-Jun-2012

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
ADS5424IPGP	ACTIVE	HTQFP	PGP	52	160	Green (RoHS & no Sb/Br)	SN	Level-3-260C-168 HR	
ADS5424IPGPR	ACTIVE	HTQFP	PGP	52	1000	Green (RoHS & no Sb/Br)	SN	Level-3-260C-168 HR	
ADS5424IPJY	OBSOLETE	QFP	PJY	52		TBD	Call TI	Call TI	
ADS5424IPJYG3	OBSOLETE	QFP	PJY	52		TBD	Call TI	Call TI	
ADS5424IPJYG4	OBSOLETE	QFP	PJY	52		TBD	Call TI	Call TI	
ADS5424IPJYR	ACTIVE	QFP	PJY	52		TBD	Call TI	Call TI	
ADS5424IPJYRG3	ACTIVE	QFP	PJY	52		TBD	Call TI	Call TI	·
ADS5424IPJYRG4	ACTIVE	QFP	PJY	52		TBD	Call TI	Call TI	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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4-Jun-2012

#### OTHER QUALIFIED VERSIONS OF ADS5424:

• Space: ADS5424-SP

NOTE: Qualified Version Definitions:

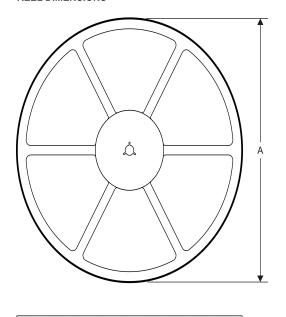
• Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

# PACKAGE MATERIALS INFORMATION

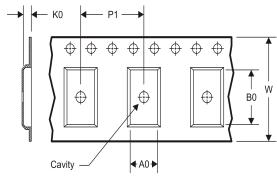
www.ti.com 7-Oct-2011

# TAPE AND REEL INFORMATION

# **REEL DIMENSIONS**







A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# TAPE AND REEL INFORMATION

# \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS5424IPGPR	HTQFP	PGP	52	1000	330.0	24.4	13.0	13.0	1.5	16.0	24.0	Q2

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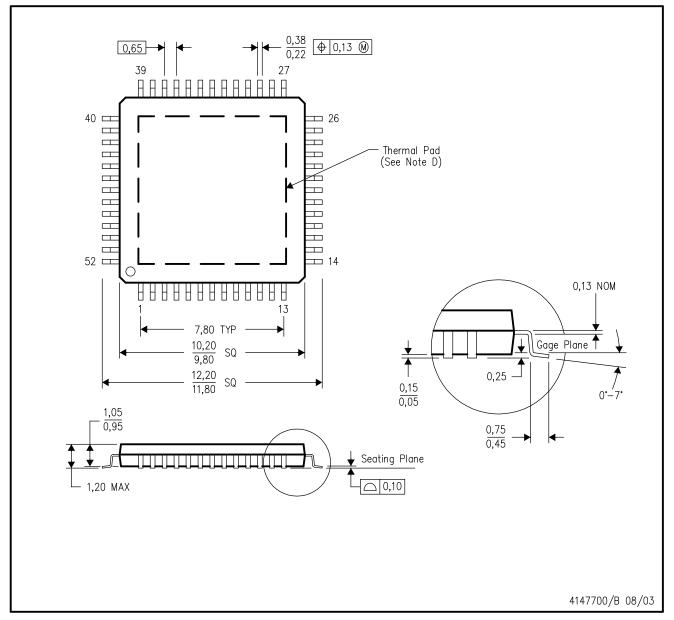


#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS5424IPGPR	HTQFP	PGP	52	1000	346.0	346.0	41.0

# PGP (S-PQFP-G52)

# PowerPAD™ PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="https://www.ti.com">www.ti.com</a>.
- E. Falls within JEDEC MS-026

PowerPAD is a trademark of Texas Instruments.



# THERMAL PAD MECHANICAL DATA



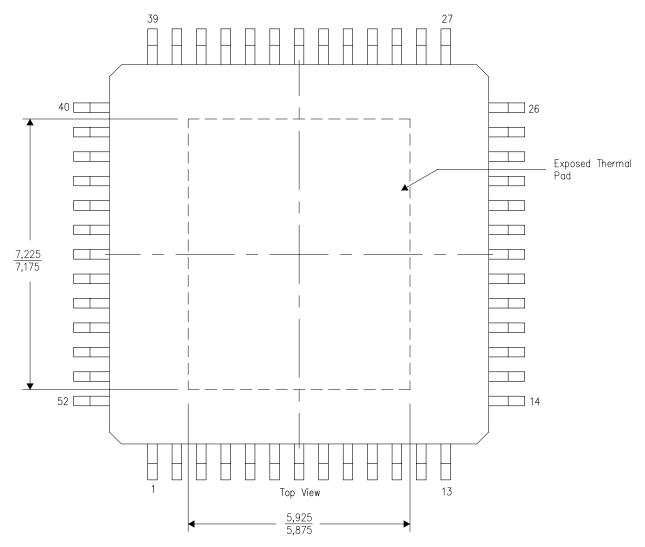
PGP (S-PQFP-G52)

#### THERMAL INFORMATION

This PowerPAD  $^{\text{M}}$  package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

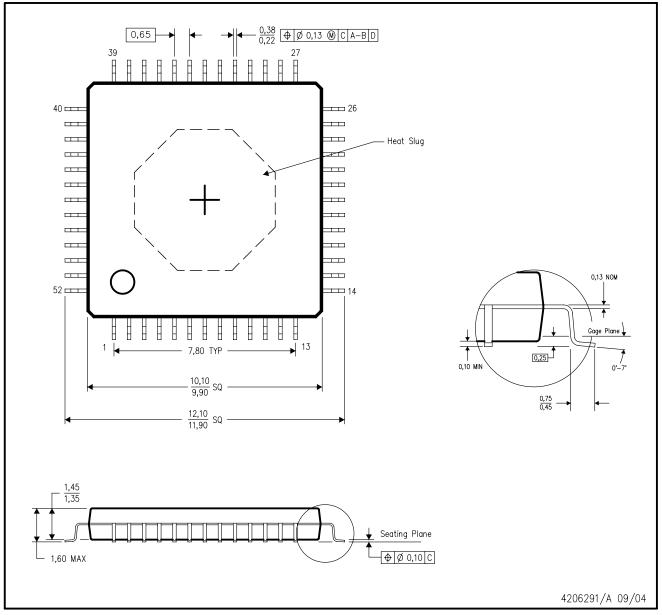
The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters

# PJY (S-PQFP-G52)

# PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com.



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